

# CPH3355 — P-Channel Silicon MOSFET

## General-Purpose Switching Device Applications

### Features

- ON-resistance  $R_{DS(on)}=120\text{m}\Omega(\text{typ.})$
- 4V drive
- Halogen free compliance

### Specifications

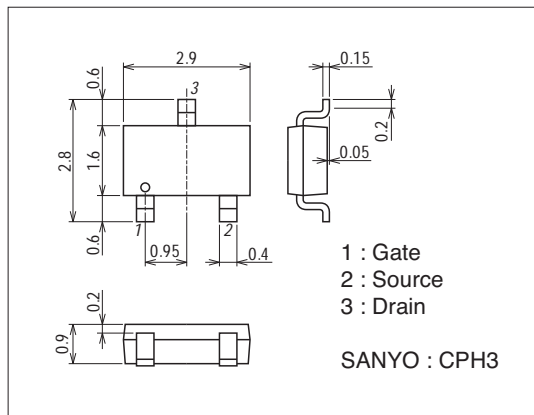
Absolute Maximum Ratings at  $T_a=25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	$V_{DSS}$		-30	V
Gate-to-Source Voltage	$V_{GSS}$		$\pm 20$	V
Drain Current (DC)	$I_D$		-2.5	A
Drain Current (Pulse)	$I_{DP}$	$PW \leq 10\mu\text{s}$ , duty cycles $\leq 1\%$	-10	A
Allowable Power Dissipation	$P_D$	When mounted on ceramic substrate (900mm <sup>2</sup> ×0.8mm)	1	W
Channel Temperature	$T_{ch}$		150	$^\circ\text{C}$
Storage Temperature	$T_{stg}$		-55 to +150	$^\circ\text{C}$

### Package Dimensions

unit : mm (typ)

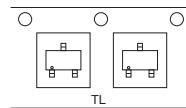
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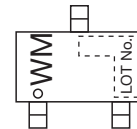
### Product & Package Information

- Package : CPH3
- JEITA, JEDEC : SC-59, TO-236, SOT-23
- Minimum Packing Quantity : 3,000 pcs./reel

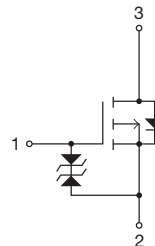
### Packing Type: TL



### Marking



### Electrical Connection

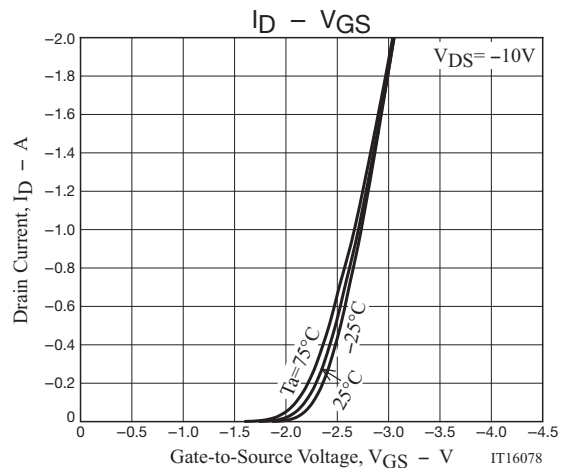
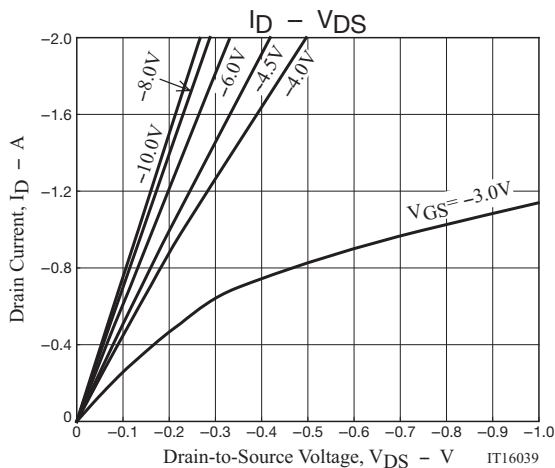
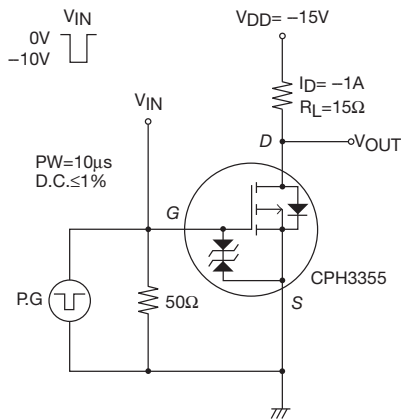


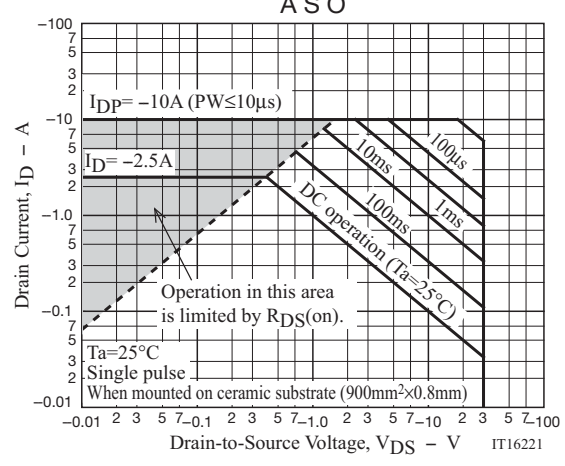
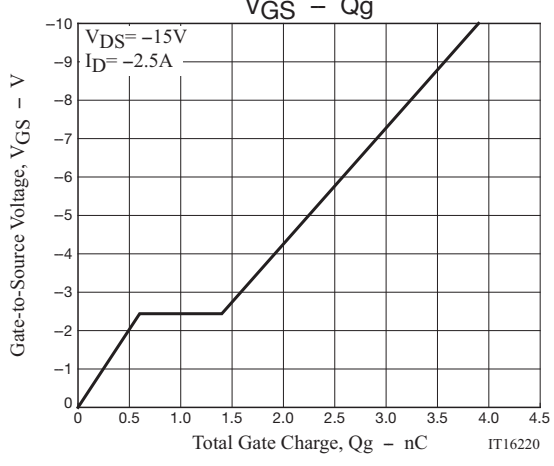
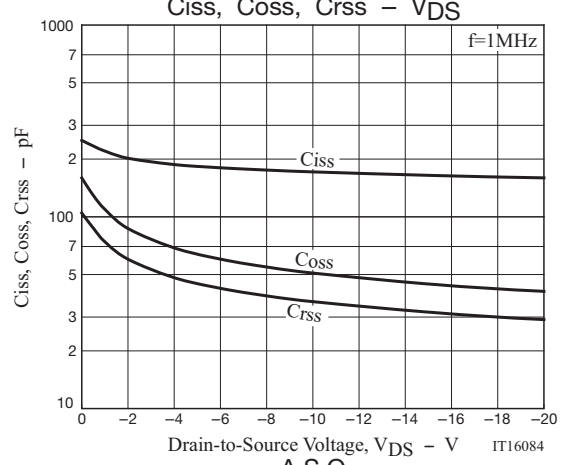
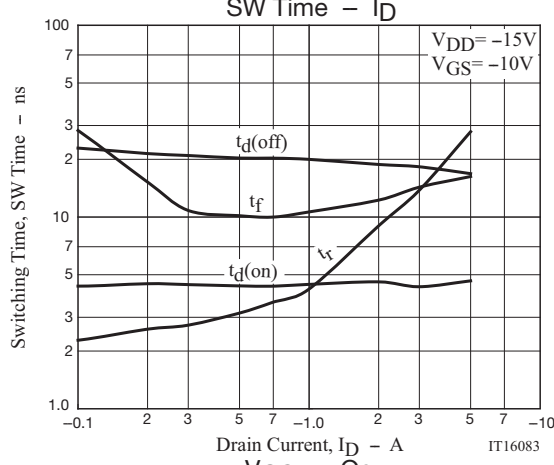
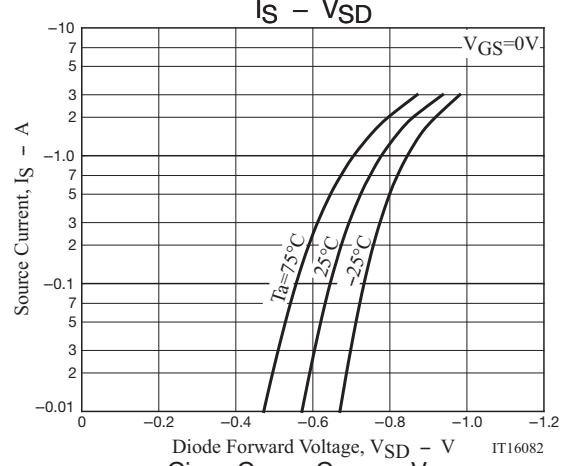
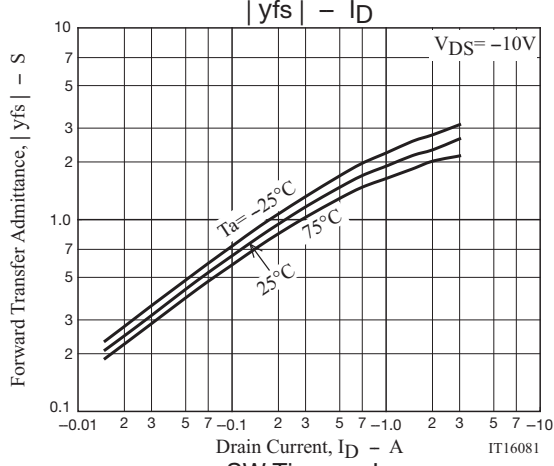
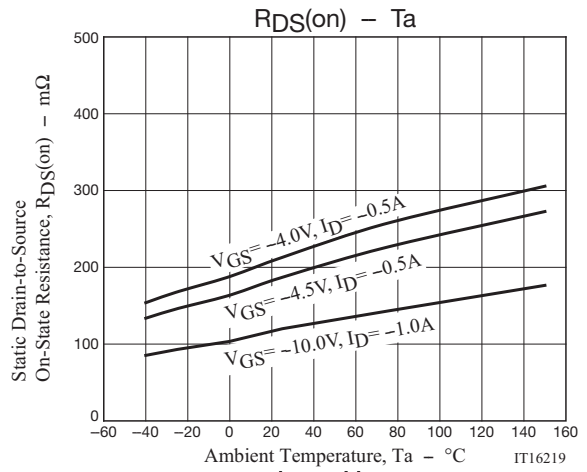
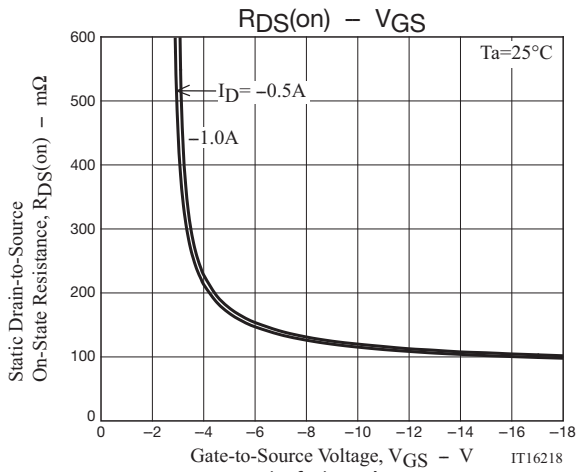
# CPH3355

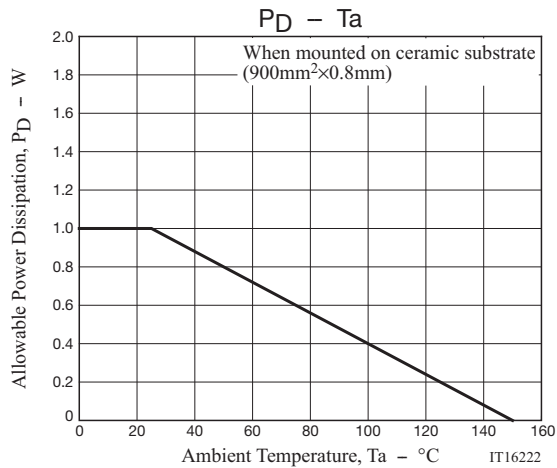
## Electrical Characteristics at $T_a=25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain-to-Source Breakdown Voltage	$V_{(BR)DSS}$	$I_D=-1\text{mA}, V_{GS}=0\text{V}$	-30			V
Zero-Gate Voltage Drain Current	$I_{DSS}$	$V_{DS}=-30\text{V}, V_{GS}=0\text{V}$			-1	$\mu\text{A}$
Gate-to-Source Leakage Current	$I_{GSS}$	$V_{GS}=\pm 16\text{V}, V_{DS}=0\text{V}$			$\pm 10$	$\mu\text{A}$
Cutoff Voltage	$V_{GS(off)}$	$V_{DS}=-10\text{V}, I_D=-1\text{mA}$	-1.2		-2.6	V
Forward Transfer Admittance	$ y_{fs} $	$V_{DS}=-10\text{V}, I_D=-1\text{A}$		1.9		S
Static Drain-to-Source On-State Resistance	$R_{DS(on)1}$	$I_D=-1\text{A}, V_{GS}=-10\text{V}$		120	156	$\text{m}\Omega$
	$R_{DS(on)2}$	$I_D=-0.5\text{A}, V_{GS}=-4.5\text{V}$		187	262	$\text{m}\Omega$
	$R_{DS(on)3}$	$I_D=-0.5\text{A}, V_{GS}=-4\text{V}$		213	299	$\text{m}\Omega$
Input Capacitance	$C_{iss}$	$V_{DS}=-10\text{V}, f=1\text{MHz}$		172		pF
Output Capacitance	$C_{oss}$	$V_{DS}=-10\text{V}, f=1\text{MHz}$		51		pF
Reverse Transfer Capacitance	$C_{rss}$	$V_{DS}=-10\text{V}, f=1\text{MHz}$		36		pF
Turn-ON Delay Time	$t_d(on)$	See specified Test Circuit.		4.5		ns
Rise Time	$t_r$	See specified Test Circuit.		4.2		ns
Turn-OFF Delay Time	$t_d(off)$	See specified Test Circuit.		20		ns
Fall Time	$t_f$	See specified Test Circuit.		10.6		ns
Total Gate Charge	$Q_g$	$V_{DS}=-15\text{V}, V_{GS}=-10\text{V}, I_D=-2.5\text{A}$		3.9		nC
Gate-to-Source Charge	$Q_{gs}$	$V_{DS}=-15\text{V}, V_{GS}=-10\text{V}, I_D=-2.5\text{A}$		0.6		nC
Gate-to-Drain "Miller" Charge	$Q_{gd}$	$V_{DS}=-15\text{V}, V_{GS}=-10\text{V}, I_D=-2.5\text{A}$		0.8		nC
Diode Forward Voltage	$V_{SD}$	$I_S=-2.5\text{A}, V_{GS}=0\text{V}$		-0.86	-1.5	V

## Switching Time Test Circuit







Note on usage : Since the CPH3355 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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